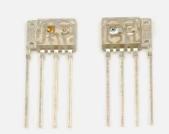
Transmitter/Receiver photo IC for optical link L10063-01, S10064-01B



For MOST automotive network, 50 Mbps band POF communications

L10063-01 and S10064-01B are transmitter and receiver photo ICs developed for MOST (Media Oriented System Transport) networks used in vehicles to communicate multimedia information. The transmitter photo IC L10063-01 consists of a red LED and driver IC incorporated into a clear plastic package and can be set to an operating mode that reduces the optical output level by half. The receiver photo IC S10064-01B is a monolithic photo IC fabricated by the PiN-BiP process and features a wide dynamic range. It also has a low power consumption "sleeping mode" and an optical wakeup mode triggered by input of light. Both the transmitter and receiver photo IC input or output digital signals through a TTL interface.

Features

L10063-01

- Wide operating temperature range: -40 to +105 °C
- DC to 50 Mbps data communications
- TTL input
- Optical output 50 % cut mode

S10064-01B

- Wide operating temperature range: -40 to +105 °C
- 4 M to 50 Mbps data communications
- Monolithic structure immune from external noise
- TTL output
- Wide dynamic range
- Sleeping mode with optical wakeup

■ Absolute maximum ratings *1 (Ta= -40 to +105 °C)

Applications

Only for vehicle networks (MOST)

	MOST	comp	oliant	products
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Specifications of these products are subject to change without prior notice to keep up with changes in the MOST standard.

Parameter	Symbol	L10063-01, S10064-01B	Unit
Supply voltage	Vcc	-0.5 to +7.0	V
Operating temperature	Topr	-40 to +105	°C
Storage temperature	Tstg	-40 to +120	°C
Soldering	Tsol	260 °C, 5 s, 3 times, at least 2.5 mm away from lead root	-

S10064-01B

Electrical and optical characteristics	$(Ta = -40 \text{ to } +105 ^{\circ}\text{C}, Vcc = 4.75 \text{ to } 5.25 \text{ V}^{*})$	
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	Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
	consumption on mode)	Icco	*2	=	-	30	m A
Current	consumption (sleeping mode)	lccs	Dark state	-	-	20	μA
Receive	er level	Popt3	Bi-phase signal	-25	-	-2	dBm
	High level output voltage	Voh	loh= -150 μm	2.5	-	Vcc+0.3	V
Mant	Low level output voltage	Vol	IoI=1.6 mA	0	-	0.4	V
Vout	Rise time	tr	10 to 90 % *2, *3	-	-	9	
	Fall time	tf	10 10 90 %	-	-	7	ns
Pulse w	idth variation	tpwv	*2, *3, *4, *6	17.9	-	29.79	ns
Pulse w	ridth distortion (average value)	tapwd	*2, *3, *4, *6	-2.69	-	+6.49	ns
Operation to sleeping mode transition receivable level		PsI	*2, *5	20		25.5	dBm
Sleeping	mode to operation transition receivable level	Pop	*2, *3	-39	-	-25.5	авт
Mode	High level voltage	Vmh	Imh= -20 μA	4.0	-	-	V
output	Low level voltage	VmI	ImI=0.88 mA	_	_	0.5	V

*1: A bypass capacitor (0.1 μF) is connected between Vcc and GND at a position within 3 mm from the lead, and a 10 μF capacitor is also connected to the power supply line nearby.

The center of the optical fiber is aligned with the center of the package lens.

The distance between the fiber end and the lens top is 0.1 mm.

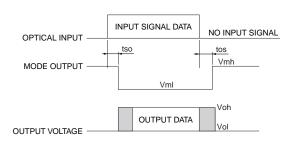
- *2: Measured with input signals conforming to SP3 MOST specification of physical layer Rev 1.1 Addendum B.
- *3: Measured with RL=50 kΩ, CL=15 pF (including parasitic capacitance such as probe, connector and evaluation circuit board pattern), and threshold voltage 1.5 V.
- *4: An optical input waveform is generated with a Hamamatsu standard transmitter.
- *5: Average optical output is measured with a POF (NA=0.5).
- *6: Measured with BiPhase PRBS at 45.2 Mbps (NRZ signal conversion).

Note) • If modulated light at 4 Mbps or less (including DC light and no light input) is input to S10064-01B, the high and low levels cannot be discerned.



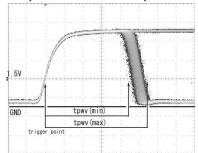
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■ Mode output waveform



KPICC0095EA

■ Output waveform example



Vertical axis: 1 V/div., Horizontal axis: 5 ns/div. (Ta=25 °C, Vcc=5.25 V, Pi= -26 dBm, RL=50 kΩ, CL=15 pF, 45.2 Mbps)

L10063-01

■ Electrical and optical characteristics (Ta= -40 to +105 °C, Vcc= 4.75 to 5.25 V *7)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Current consumption	Icc	Vin= 2.0 V, Rcont=13.5 kΩ	ı	-	40	mA
Peak emission wavelength	λр		630	650	670	nm
Spectral half width (FWHM)	Δλ		-	20	30	nm
Fiber coupled optical output 1	Po1	Rcont=13.5 kΩ *8, *9	-9	-	-2	dBm
Fiber coupled optical output 2	Po2	Rcont=27 kΩ *8, *9	-12.5	-	-4.5	dBm
Extinction ratio	re		10	-	-	dB
Rise time at pulse drive	tr	20 to 80 % *8	-	-	6.0	ns
Fall time at pulse drive	tf	80 to 20 % *8	-	-	6.0	ns
Pulse width variation	tpwv	50 % *8, *10	19.99	-	24.29	ns
Pulse width distortion (average value)	tapwd	50 % *8, *10	-1.39	-	+1.39	ns

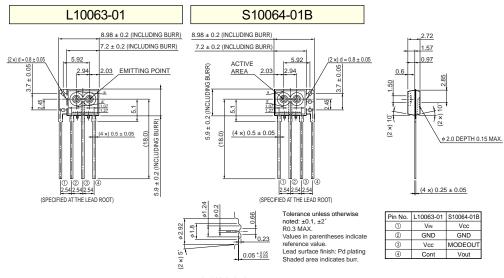
^{*7:} A bypass capacitor (0.1 μF) connected between Vcc and GND at a position within 3 mm from the lead, and a 10 μF capacitor is also connected to the power supply line nearby.

The center of the optical fiber is aligned with the center of the package lens.

The distance between the fiber end and the lens top is 0.1 mm.

- *8: Measured with input signals conforming to SP1 MOST specification of physical layer Rev 1.1 Addendum B.
- *9: Average value measured with a plastic fiber (¢1 mm, SI-POF, NA=0.5, 1 m) made by Mitsubishi Rayon.
- *10: Measured with BiPhase PRBS at 45.2 Mbps (NRZ signal conversion).

■ Dimensional outlines (unit: mm)



a-a' CROSS SECTION

KPICA0067EB

Information furnished by HAMAMATSU is believed to be reliable. However, no responsibility is assumed for possible inaccuracies or omissions.

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